Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Ma	terial:
Metal	
Overall Leng	th:
Between 0.33	0 inches and 0.505 inches
Mounting Fa	cility Quantity:
1	
Internal Conf	iguration:
Junction conta	act
Joint Electro	nic Device Engineering Council/jedec/case Outline Designation:
To-48	
Electrode Int	ernally-electrically Connected To Case:
Anode	
Mounting Me	thod:
Threaded stud	t
Overall Width	n Across Flats:
Between 0.54	4 inches and 0.562 inches
Thread Size:	
0.250 inches	
Semiconduc	tor Material:
Silicon	
Voltage Ratir	ng In Volts Per Characteristic:
25.0 repetitiv	e peak reverse voltage
Current Ratir	ng Per Characteristic:
25.00 ampere	s forward current, average of standard range
Power Rating	y Per Characteristic:
5.0 watts sma	II-signal input power, common-collector blank
Maximum Op	perating Tempurature Per Measurement Point:
125.0 degrees	s celsius junction
Special Featu	ures:
Small termina	I gate connected and large terminal cathode connected; junction pattern arrangement: npn
Thread Serie	s Designator:
Unf	
Terminal Typ	e And Quantity:
1 threaded stu	ud and 2 tab, solder lug
Shelf Life:	
N/a	
Unit Of Meas	ure:
 Demilitarizati	
No	
Fiig: A110a0	